

First results on Timing
Performance of Monolithic
sensors with additional gain for
the future ALICE 3 experiment

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on behalf of the ALICE and the ARCADIA Collaborations

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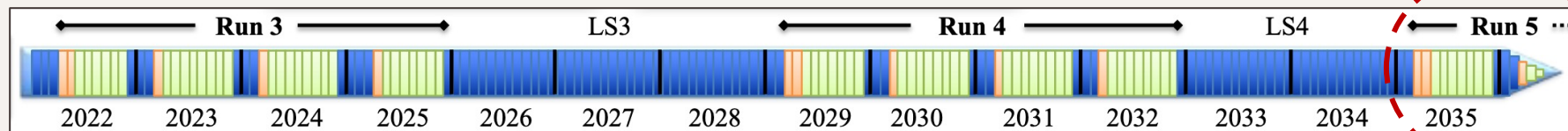
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01

Introduction



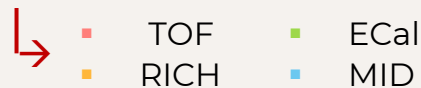
ALICE 3: a next generation heavy ion experiment



ALICE 3

Key features:

- exceptional pointing resolution
- excellent Particle IDentification (PID)

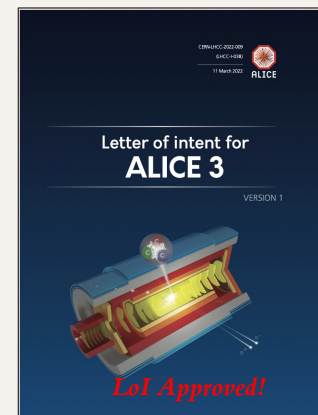
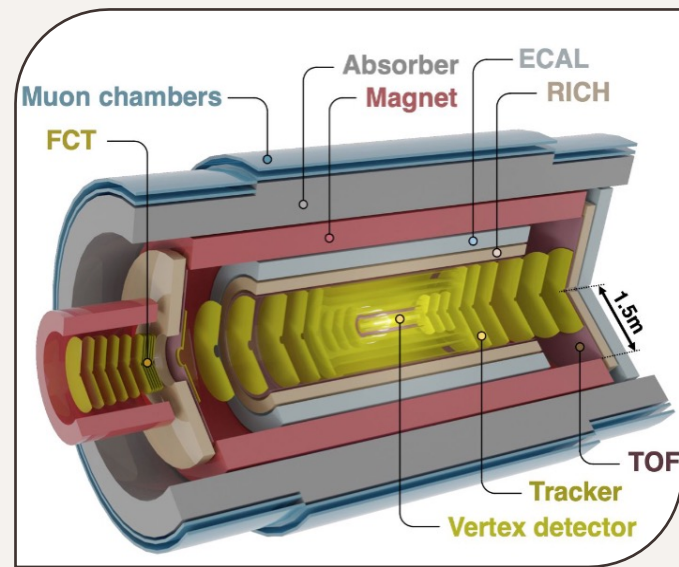


Time-Of-Flight (TOF) system with silicon sensor

→ electrons and hadrons ID at low p_T

Requirements:

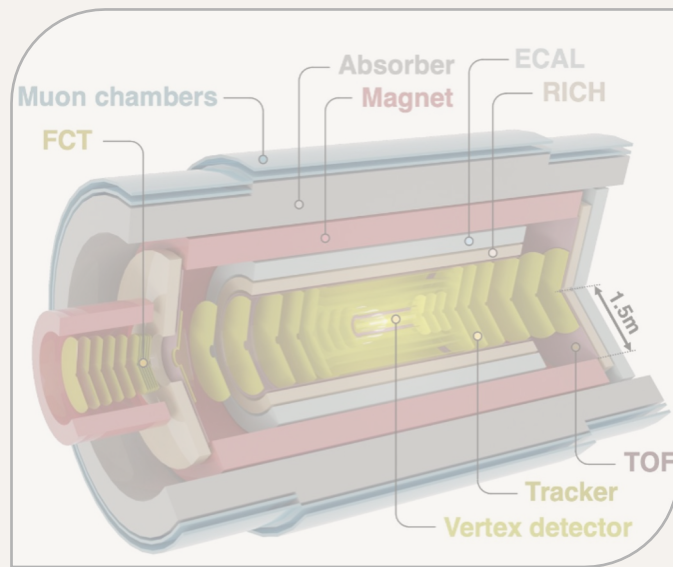
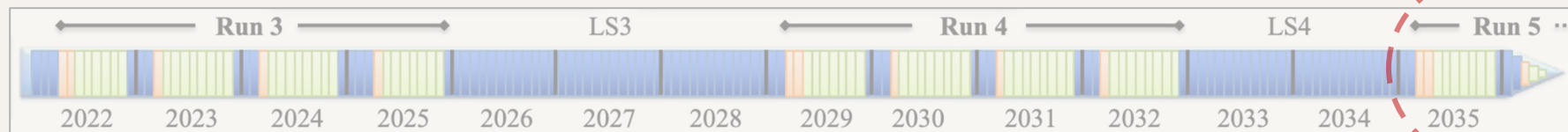
- » time resolution of 20 ps
- » low material budget $\sim 1\text{-}3\%$ X_0 per layer
- » low power density 50 mW/cm²



<https://cds.cern.ch/record/2803563>



ALICE 3: a next generation heavy ion experiment



Key features:

- exceptional pointing resolution
- excellent Particle IDentification (PID)

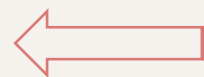
- | | | |
|---|--------|--------|
| ↳ | ▪ TOF | ▪ ECal |
| | ▪ RICH | ▪ MID |

Time-Of-Flight (TOF) system with silicon sensor

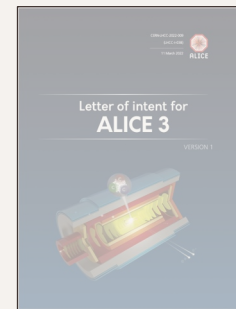
→ electrons and hadrons ID at low p_T

Requirements:

- » time resolution of 20 ps *HOW?*
- » low material budget $\sim 1\text{-}3\% X_0$ per layer
- » low power density 50 mW/cm²



ALICE 3



3 options considered in Lol:

- CMOS Sensors
- LGADs
- SPADs



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Monolithic sensors – ARCADIA Project


<https://web.infn.it/ARCADIA/index.php/en>

Advanced Readout CMOS Architectures with Depleted Integrated sensor Arrays

- » **Front-end electronics** is embedded in the same silicon substrate → **Lower material budget + Cheaper**
- » **Fully depleted monolithic sensor** → fast charge collection by drift → good time performance
- » **Large electrode** → uniform \vec{E} necessary for timing measures
→ higher capacitance → **Signal-to-Noise Ratio decreases**

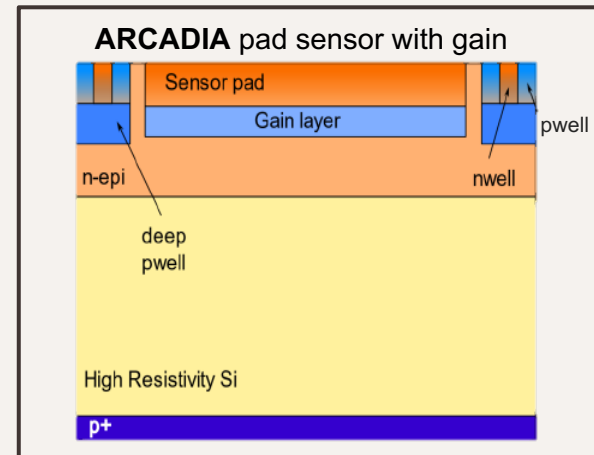
- » **Drawback:** current time resolution is too low (\sim ns)



Solution: *gain layer* with low multiplication introduction

charge multiplication → avalanche process

increase the signal/noise ratio (SNR)



Lucio Pancheri



MadPix

Monolithic CMOS Avalanche Detector **PIX**elated Prototype

First prototype with **integrated electronics** and **gain layer**

↳ LFoundry in 110 nm commercial CMOS Process

Active thickness: 48 μm

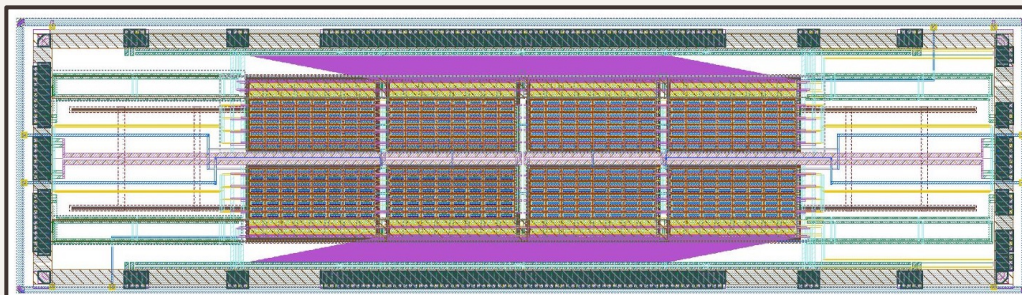
- **Backside HV**: allow full depletion \rightarrow -25 V to -40 V
- **Topside HV**: manage the gain \rightarrow 30 V to 50 V

» 8 matrices of 64 pixels each

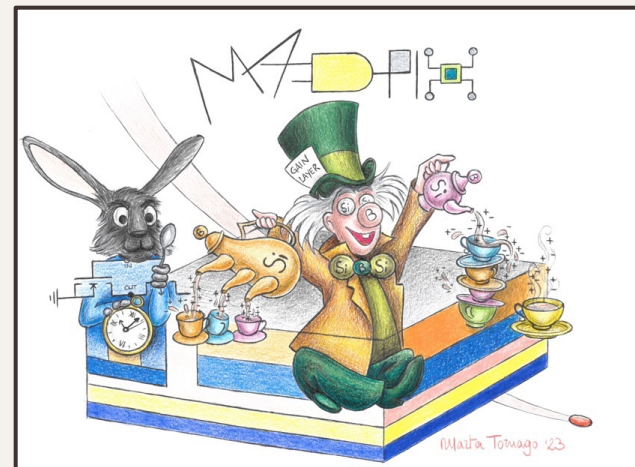
» 64 x 2 analogue outputs

» 4 flavours

» Pixels of 250 μm x 100 μm



↕ Symmetrical



Thanks to M. Tornago



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02

Monte Carlo Simulation



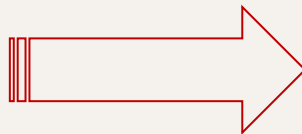
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Allpix² tool

<https://allpix-squared.docs.cern.ch/>

TCAD

- Simulation tool for sensor modeling
- Describes electromagnetic fields
- Long computing time

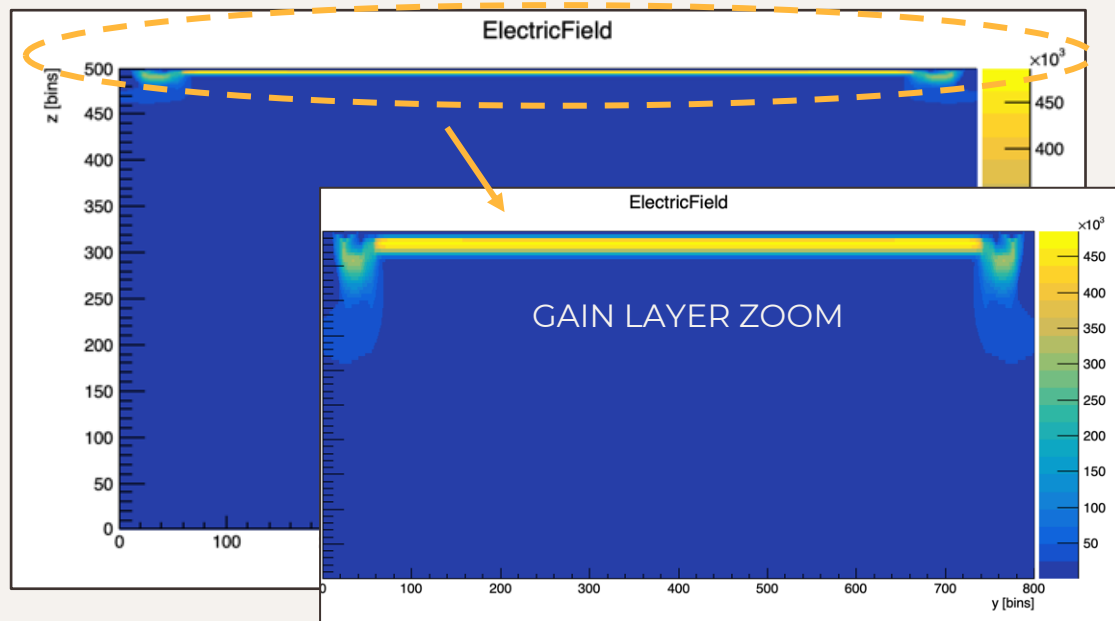


Allpix²

- Monte Carlo simulations for detectors
- High statistics
- Less computing time

2D Simulation

- Pixel size: $80 \times 50 \mu\text{m}^2$
 $80\mu\text{m}$ width \rightarrow $68\mu\text{m}$ effective width of the gain layer
- $50\mu\text{m}$ thickness
- Mesh division: $0.1 \times 0.1 \mu\text{m}^2$
- Squared source with $2 \mu\text{m}$ square side
- Charged particle: **180 GeV π**
- **Masetti-Canali** mobility model
- Multiplication model: **Okuto**

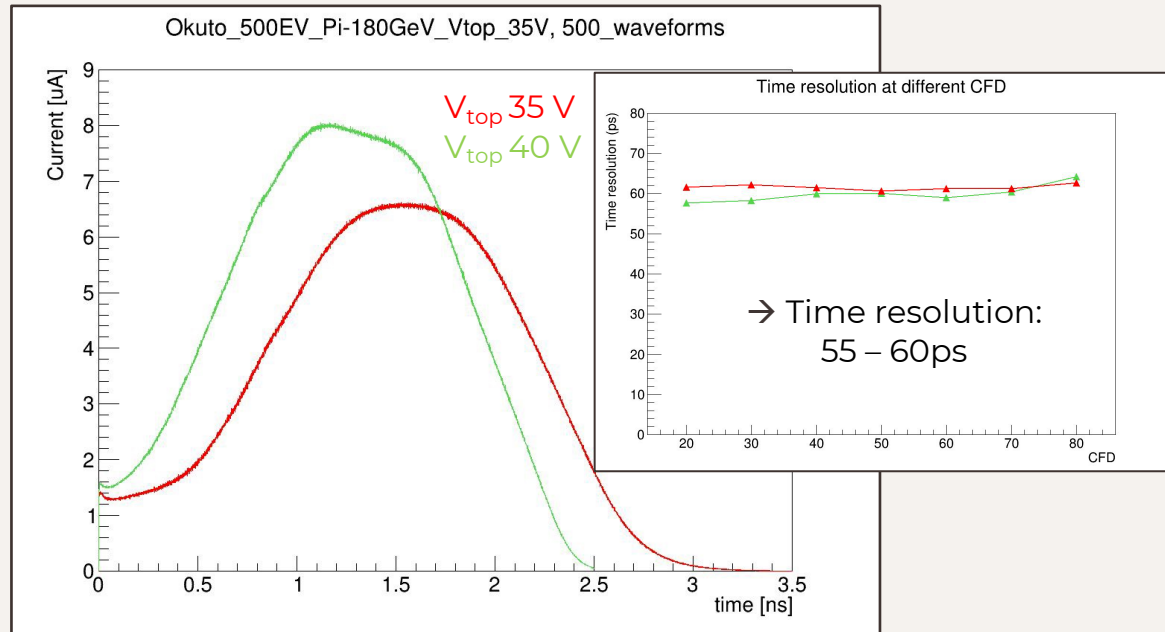
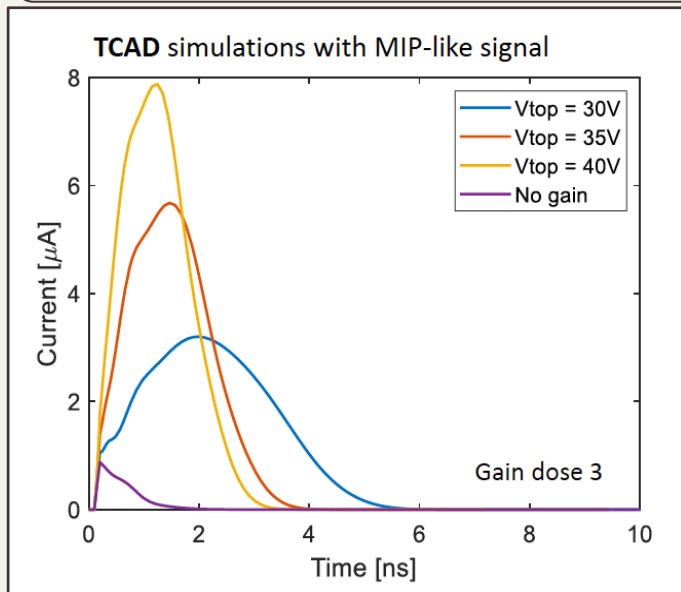




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Allpix² tool

Comparison between Allpix² and TCAD signals at different V_{top} bias

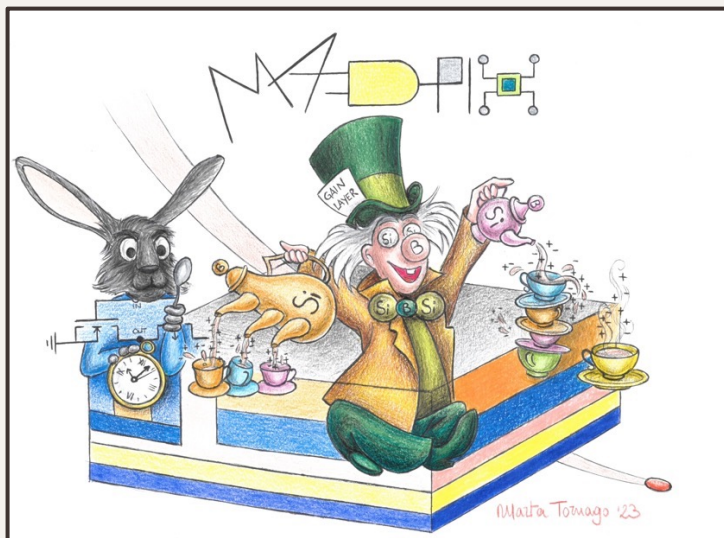


We are a bit far from the time resolution required by ALICE 3

- the electric field will be more uniform increasing the sensor width → improves the time resolution
- thickness reduction (25 -15 μm) is needed to reach the 20ps target

03

Laboratory Tests



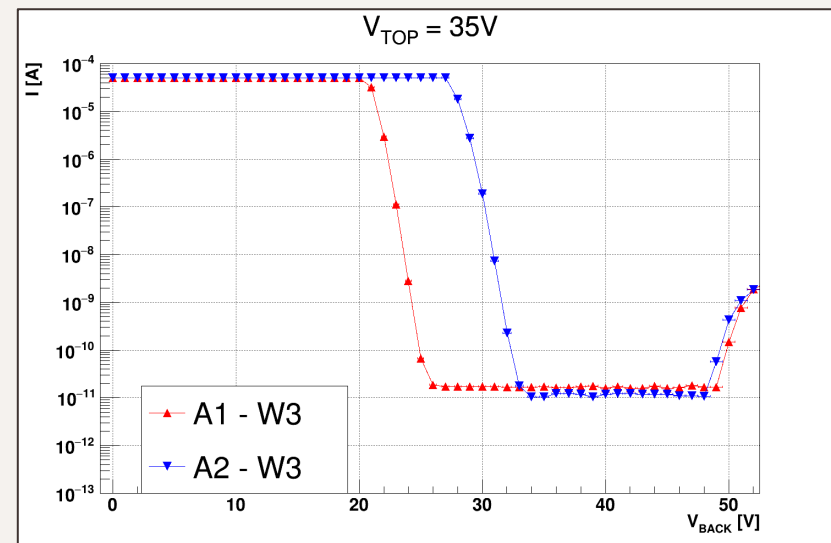
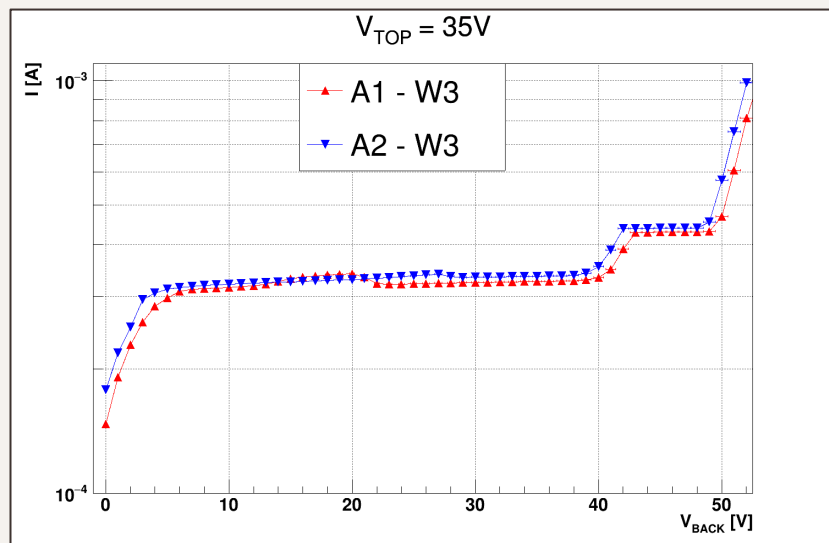


Passive structures characterization

I(V) scan to study the sensor behavior

I_{back} → current between p⁺ on the backside and the p-wells
→ Punch through for HV back > 45V

I_{top} → current between n⁺ collection electrode and guard ring
→ Depletion for HV back > 35V





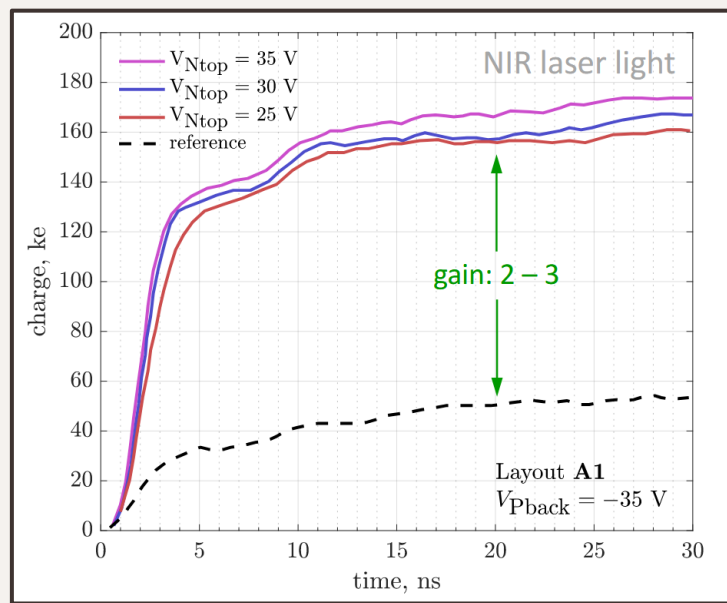
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Laser Measurements

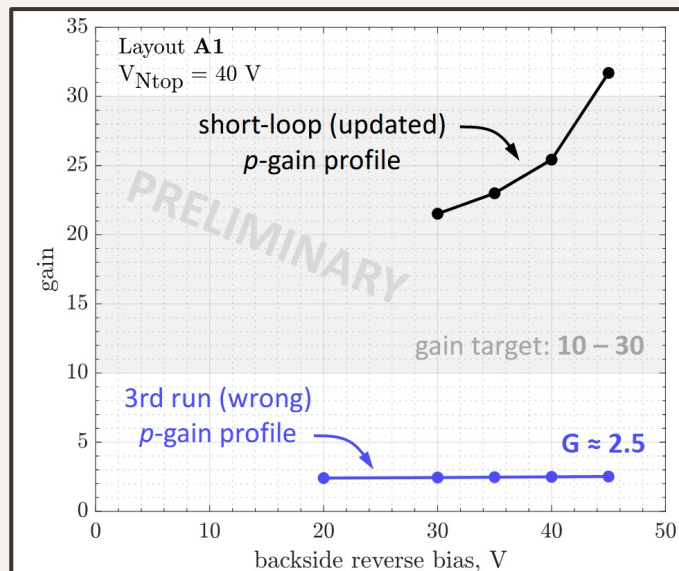
Optical characterization at UNITN (Trento)

- IR laser from the back of the sensor
- laser spot $\sim 20 \mu\text{m}$

Integral of the charge \rightarrow Gain ≈ 2.5



Investigation of the p-gain profile with TCAD



Implantation energy
lower by 30%
with respect to the
design



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04

Conclusions



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Conclusions and Outlook

→ A new innovative sensor is being designed and tested to meet the timing requirement of ALICE 3 Project

↳ **Monolithic sensors with additional gain**

→ Using a Monte Carlo simulation tool **Allpix²**

↳ the electrical behavior and the timing performance are being simulated

A time resolution of about 50 ps is obtained → thinning the sensor we could achieve the required 20 ps

→ Prototype for timing application in 110nm technology design in the ARCADIA project

↳ **MadPix**

→ Laboratory tests show that the sensors are **fully functional**

What's next?

→ Simulation activities in parallel with tests

→ Short loop run will arrive in the next weeks: new sensors with increased gain to be tested

Thank you for the attention!



ALICE

Spare



Monolithic sensors – ARCADIA Project



<https://web.infn.it/ARCADIA/index.php/en>

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→ higher capacitance → **noise increases**

$$\sigma_t^2 = \sigma_{\text{Time Walk}}^2 + \sigma_{\text{Landau Noise}}^2 + \sigma_{\text{Distortion}}^2 + \sigma_{\text{Jitter}}^2 + \sigma_{\text{TDC}}^2$$

Fundamental limit
 Non saturated velocity and non-uniform weighting field
 Can be made negligible

Can be **corrected** (e.g. with Constant Fraction Discriminator, CFD)

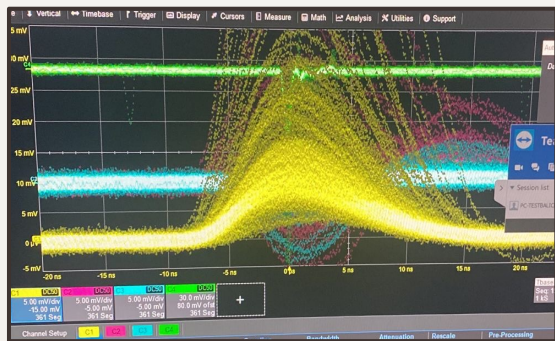
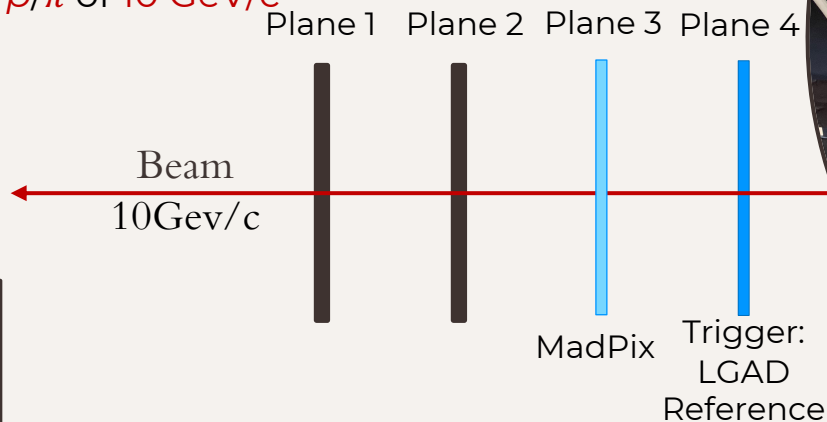
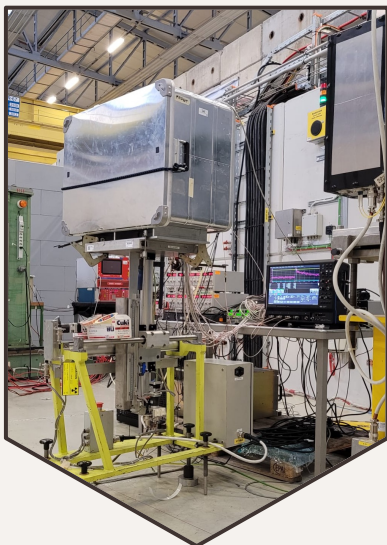
$$\sigma_{\text{Jitter}} \propto \frac{\sigma_V}{\frac{dV}{dt}}$$

{ Low input capacitance,
 High preamp. transconductance
 → Large signal (gain)
 → Short signal rise time

H. F.-W. Sadrozinski et al 2018 Rep. Prog. Phys. 81 026101

Test Beam Setup

- 📍 Test beam setup realized at INFN Bologna
- In October 2023 **first test beam** with **MadPix**
- at CERN Proton Synchrotron (PS)
- with p/π of 10 GeV/c



First MIP signals of MadPix